Docket No.

214391US2S

IN RE APPLICATION OF:

Hidetaka HATTORI

SERIAL NO:

09/961,248

FILED:

September 25, 2001

FOR:

POWER SEMICONDUCTOR DEVICE AND MANUFACTURING METHOD THEREOF IECHIULUET CEHTER 2800

ASSISTANT COMMISSIONER FOR PATENTS WASHINGTON, D.C. 20231

SIR:

Transmitted herewith is an amendment in the above-identified application.

No additional fee is required

☐ Small entity status of this application under 37 C.F.R. §1.9 and §1.27 is claimed.

Additional documents filed herewith:

Marked-Up Copy

The Fee has been calculated as shown below:

CLAIMS	CLAIMS REMAINING		HIGHEST NUMBER PREVIOUSLY PAID	NO. EXTRA CLAIMS		RATE		CALCULATIONS
TOTAL	40	MINUS	40	0	х	\$18	=	\$0.00
INDEPENDENT	4	MINUS	4	0	х	\$84	=	\$0.00
		☐ MULTIPLE DEPENDENT CLAIMS + \$280 =				=	\$0.00	
,			TOTAL OF	ABOVE CAI	CU	LATIO	NS	\$0.00
		☐ Reduction	by 50% for filing	by Small Enti	ty			\$0.00
		☐ Recordati	on of Assignment		+	\$40	=	\$0.00
l						TOT	ΑL	\$0.00

☐ A check in the amount of	<u>\$0.00</u>	is attached.
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- Please charge any additional Fees for the papers being filed herewith and for which no check is enclosed herewith, or credit any overpayment to deposit Account No. 15-0030. A duplicate copy of this sheet is enclosed.
- ☑ If these papers are not considered timely filed by the Patent and Trademark Office, then a petition is hereby made under 37 C.F.R. §1.136, and any additional fees required under 37 C.F.R. §1.136 for any necessary extension of time may be charged to Deposit Account No. 15-0030. A duplicate copy of this sheet is enclosed.

OBLON, SPIVAK, McCLELLAND, MAIER & NEUSTADT, P.C.

"RESPONSE UNDER 37 CFR 1.116-

GROUP 2814 "

EXPEDITED PROCEDURE EXAMINING

22850

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"RESPONSE UNDER 37 CFR 1.116-EXPEDITED PROCEDURE EXAMINING GROUP 28/4"

## IN THE UNITED STATES PATENT & TRADEMARK OFFICE

IN RE APPLICATION OF

:

HIDETAKA HATTORI

: EXAMINER: FARAHANI, D.

SERIAL NO: 09/961,284

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FILED: SEPTEMBER 25, 2001

: GROUP ART UNIT: 2814

FOR: POWER SEMICONDUCTOR

DEVICE AND MANUFACTURING

METHOD THEREOF

**AMENDMENT** 

ASSISTANT COMMISSIONER FOR PATENTS

WASHINGTON, D.C. 20231

SIR:

In response to the Office Action dated August 27, 2002, please amend the aboveidentified application as follows:

## IN THE CLAIMS

Please amend Claims 1-40 as shown in clean form below.1

1. (Three Times Amended) A power semiconductor device comprising:

a base layer of a first conductivity type;

a base layer of a second conductivity type selectively formed on one surface of said

base layer of the first conductivity type;

<sup>&</sup>lt;sup>1</sup>A marked-up copy of the amended portion of the claims is attached hereto.